





CD4027B SCHS032D - NOVEMBER 1998 - REVISED JULY 2021

CD4027B CMOS Dual J-K Flip Flop

1 Features

- Set-reset capability
- Static flip-flop operation retains state indefinitely with clock level either high or low
- Medium speed operation 16 MHz (typical) clock toggle rate at 10 V
- Standardized symmetrical output characteristics
- 100% tested for quiescent current at 20 V
- Maximum input current of 1 µA at 18 V over full package-temperature range; 100 nA at 18 V and 25°C
- Noise margin (over full package-temperature range):
 - $1 V at V_{DD} = 5 V$
 - 2 V at V_{DD} = 10 V
 - 2.5 V at V_{DD} = 15 V
- 5 V, 10 V, and 15 V parametric ratings
- Meets all requirements of JEDEC tentative standard No. 138, standard specifications for description of 'B' series CMOS devices

2 Applications

Registers, counters, control circuits

3 Description

CD4027B is a single monolithic chip integrated circuit containing two identical complementary-symmetry J-K flip flops. Each flip-flop has provisions for individual J, K, Set, Reset, and Clock input signals. Buffered Q and \overline{Q} signals are provided as outputs. This inputoutput arrangement provides for compatibile operation with the RCA-CD4013B dual D-type flip-flop.

The CD4027B is useful in performing control, register, and toggle functions. Logic levels present at the J and K inputs along with internal self-steering control the state of each flip-flop; changes in the flip-flop state are synchronous with the postitive-going transition of the clock pulse. Set and reset functions are independent of the clock and are initiated when a high level signal is present at either the Set or Reset input.

The CD4027B types are supplied in 16-lead hermetic dual-in-line ceramic packages (F3A suffix), 16-lead dual-in-line plastic packages (E suffice), 16-lead small-outline packages (M, M96, MT, and NSR suffixes), and 16-lead thin shrink small-outline packages (PW and PWR suffixes).

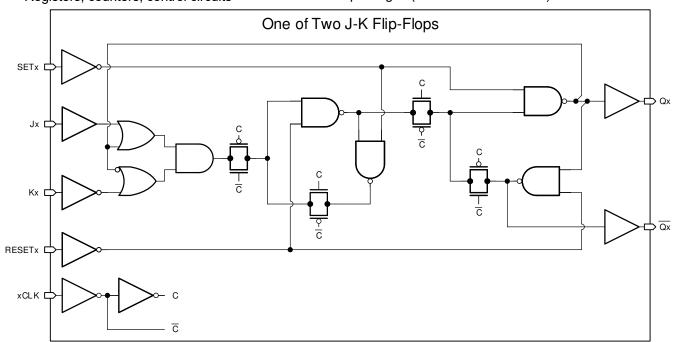


Figure 3-1. Logic Diagram



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4 Revision History

NOTE: Page numbers for previous revisions may differ from page numbers in the current version.

Changes from Revision C (October 2003) to Revision D (July 2021)

Page

• Updated the numbering format for tables, figures, and cross-references throughout the document......1

5 Pin Configuration and Functions

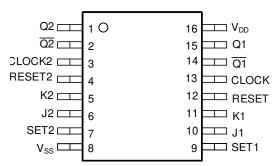


Figure 5-1. Terminal Assignment

Table 5-1. Pin Functions

F	PIN	I/O	DESCRIPTION					
NAME	NO.	1 1/0	DESCRIPTION					
CLOCK1	13	I	Clock input for channel 1					
CLOCK2	3	I	Clock input for channel 2					
J1	10	I	J input for channel 1					
J2	6	I	J input for channel 2					
K1	11	I	K input for channel 1					
K2	5	I	K input for channel 2					
Q1	15	0	Q output for channel 1					
Q1	14	0	Inverted Q output for channel 1					
Q2	1	0	Q output for channel 2					
Q2	2	0	Inverted Q output for channel 2					
RESET1	12	I	Reset input for channel 1					
RESET2	4	I	Reset input for channel 2					
SET1	9	I	Set input for channel 1					
SET2	7	I	Set input for channel 2					
V _{DD}	16	_	Supply					
V _{SS}	8	_	Ground					



6 Specifications

6.1 Absolute Maximum Ratings

			MIN	MAX	UNIT
V_{DD}	DC Supply Voltage Range	Voltages referenced to V _{SS} Terminal	-0.5	20	V
All Inputs	Input Voltage Range		-0.5	V _{DD} + 0.5	V
Any One Input	DC Input Current			±10	mA
Б	P _D Power Dissipation per Package	For T _A = -55°C to + 100°C		500	mW
FD		For T _A = +100°C to +125°C	12mW/°C	200	mW
	Device Dissipation per Output Transistor	For T _A = Full package-temperature range (all package types)		100	mW
T _A	Operating- Temperature Range		- 55	125	°C
T _{stg}	Storage temperature		-65	150	°C
	Lead Temperatur (During Soldering)	At distance 1/16 ± 1/32 inch (1.59 ± 0.79mm) from case for 10s max		265	°C

6.2 Recommended Operating Conditions

at $T_A = 25$ °C, except as noted. For maximum reliability, nominal operating conditions should be selected so that operation is always within the following ranges:

				LIN	IITS		
	CHARACTERISTIC		V _{DD} (V)	ALL PAG	CKAGES	UNIT	
			(*)	MIN	MAX		
	Supply-Voltage Range	For T _A = Full Package Temperature Range		3	18	V	
			5	200			
t _S	Data Setup Time		10	75		ns	
			15	50			
	t _W Clock Pulse Width		5	140			
t _W			10	60		ns	
			15	40			
			5		3.5		
f _{CL}	Clock Input Frequency (Toggle Mode)		10	dc	8	MHz	
			15		12		
			5		45		
t _r CL, t _f CL ⁽¹⁾	Clock Rise or Fall Time		10		5	μs	
1,02	GEV /		15		2		
			5	180			
t _W	Set or Reset Pulse Width		10	80		ns	
			15	50			

⁽¹⁾ If more than one unite is cascaded in a parallel clocked operation, t_rCL should be made less than or equal to the sum of the fixed propagation delay time at 15 pF and the transitiopn time of the output driving stage for the estimated capacitive load.

6.3 Static Electrical Characteristics

	TES	T CONDITION	NS	LIN	IITS AT	INDICA	TED TEI	MPERAT			
CHARACTERISTIC	Vo	V _{IN}	V _{DD}	-55	-40	+85	+125		+25		UNIT
	(V)	(V)	(V)	-55	-40	700	T125	MIN	TYP	MAX	
Quiescent		0, 5	5	1	1	30	30		0.02	1	
Device		0, 10	10	2	2	60	60		0.02	2	
Current		0, 15	15	4	4	120	120		0.02	4	μa
I _{DD} Max.		0, 20	20	20	20	600	600		0.04	20	
Output Low (Sink)	0.4	0, 5	5	0.64	0.61	0.42	0.36	0.51	1		
Current	0.5	0, 10	10	1.6	1.5	1.1	0.9	1.3	2.6		mA
I _{OL} Min.	1.5	0, 15	15	4.2	4	2.8	2.4	3.4	6.8		
Output High	4.6	0, 5	5	-0.64	-0.61	-0.42	-0.36	-0.51	-1		
(Source)	2.5	0, 5	5	-2	-1.8	-1.3	-1.15	-1.6	-3.2		mA
Current	9.5	0, 10	10	-1.6	-1.5	-1.1	-0.9	-1.3	-2.6		IIIA
I _{OH} Min.	13.5	0, 15	15	-4.2	-4	-2.8	-2.4	-3.4	-6.8		
Output Voltage		0, 5	5		0.	05			0	0.05	
Low-Level		0, 10	10		0.	05			0	0.05	V
V _{OL} Max.		0, 15	15		0.	05			0	0.05	
Output Voltage		0, 5	5		4.	95		4.95	5		
High-Level		0, 10	10		9.	95		9.95	10		V
V _{OH} Min.		0, 15	15		14	.95		14.95	15		
Input Low	0,5, 4.5		5		1	.5				1.5	
Voltage	1, 9		10		;	3				3	V
V _{IL} Max.	1.5, 13.5		15			4				4	
Input High	0.5, 4.5		5		3	.5		3.5			
Voltage	1, 9		10			7		7			V
V _{IH} Min.	1.5, 13.5		15		1	11		11			
Input Current, V _{IH} Max.		0, 18	18	±0.1	±0.1	±1	±1		±10 ⁻⁵	±0.1	μΑ

6.4 Dynamic Electrical Characteristics

at T_A = 25°C; Input t_r , t_f = 20 ns, C_L = 50 pF, R_L = 200 k Ω

	.,		UNIT					
CHARACTERISTIC	V _{DD} (V)	Al						
	(-)	MIN	TYP	MAX				
Propagation Delay Time	5		150	300				
Clock to Q or Q Outputs	10		65	130	ns			
t _{PHL} , t _{PLH}	15		45	90				
	5		150	300				
Set to Q or Reset to Q, t _{PLH}	10		65	130	ns			
	15		45	90	1			
	5		200	400				
Set to $\overline{\mathbb{Q}}$ or Reset to \mathbb{Q} , t_{PHL}	10		85	170	ns			
	15		60	120				
Towards Time	5		100	200				
Transition Time t_{THL}, t_{TLH}	10		50	100	ns			
יונה יונה	15		40	80				



6.4 Dynamic Electrical Characteristics (continued)

at T_A = 25°C; Input t_r , t_f = 20 ns, C_L = 50 pF, R_L = 200 k Ω

	.,		LIMITS				
CHARACTERISTIC	V _{DD} (V)	Δ	LL PACKAGE	S	UNIT		
	(*)	MIN	TYP MAX				
Maximum Clock Input	5	3.5	7				
Frequency (Toggle Mode) ⁽¹⁾	10	8	16		MHz		
f_CL	15	12	24				
	5		70	140			
Minimum Clock Pulse Width, t _W	10		30	60			
	15		20	40			
	5		90	180			
Minimum Set or Reset Pulse Width, t _W	10		40	80	ns		
	15		25	50	-		
	5		100	200			
Minimum Data Setup Time, t _S	10		35	75	ns		
	15		25	50			
Ole als largest Discours Fall Time	5			45			
Clock Input Rise or Fall Time t _{rCL} , t _{rCL}	10			5	μs		
40L, 40L	15			2	1		
Input Capacitance, C _I			5	7.5	pF		

⁽¹⁾ Input t_r , $t_f = 5$ ns

6.5 Typical Characteristics

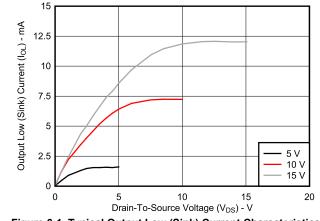


Figure 6-1. Typical Output Low (Sink) Current Characteristics

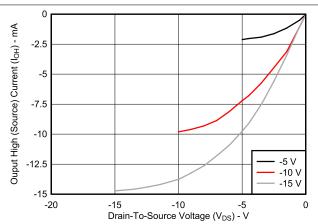


Figure 6-2. Typical Output High (Source) Current Characteristics

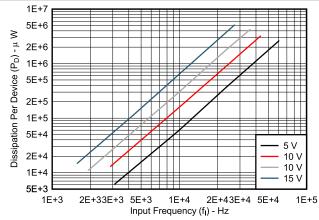


Figure 6-3. Typical Power Dissipation vs Frequency

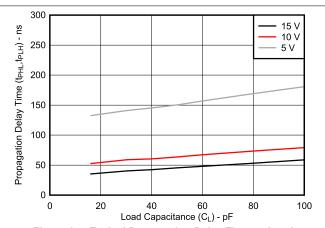


Figure 6-4. Typical Propagation Delay Time vs Load Capacitance (Clock or Set to Q, Clock or Reset to $\overline{\bf Q}$)

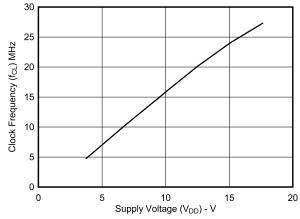


Figure 6-5. Typical Maximum Clock Frequency vs Supply Voltage (Toggle Mode)



7 Parameter Measurement Information

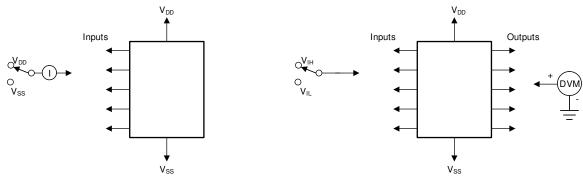


Figure 7-1. Input Current Test Circuit

Figure 7-2. Input-Voltage Test Circuit

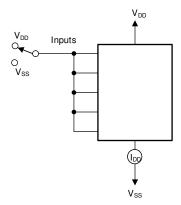
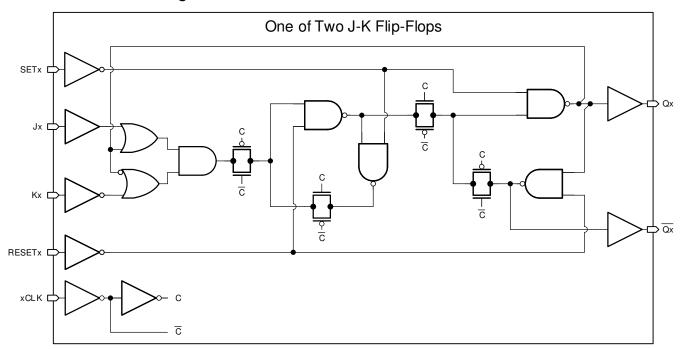


Figure 7-3. Quiescent Device Current Test Circuit



8 Detailed Description

8.1 Functional Block Diagram



8.2 Device Functional Modes⁽¹⁾

		PRESENT STATE		CL ⁽²⁾	NEXT STATE		
	INP	UTS	OUTPUT	CL(=/	OUT	PUTS	
J	K	S	R	0		0	Ō
I	X	0	0	0		I	0
Х	0	0	0	I		I	0
0	X	0	0	0		0	I
Х	I	0	0	I		0	I
Х	X	0	0	Х		No change	No change
Х	X	I	0	X	X	I	0
Х	Х	0	I	X	X	0	I
Х	X	I	I	X	X	I	I

- (1) Logic I = High Level, Logic O = Low Level, X = Do not care
- (2) Level change



9 Device and Documentation Support

TI offers an extensive line of development tools. Tools and software to evaluate the performance of the device, generate code, and develop solutions are listed below.

9.1 Receiving Notification of Documentation Updates

To receive notification of documentation updates, navigate to the device product folder on ti.com. Click on *Subscribe to updates* to register and receive a weekly digest of any product information that has changed. For change details, review the revision history included in any revised document.

9.2 Support Resources

TI E2E[™] support forums are an engineer's go-to source for fast, verified answers and design help — straight from the experts. Search existing answers or ask your own question to get the quick design help you need.

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9.3 Trademarks

TI E2E™ is a trademark of Texas Instruments.

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9.4 Electrostatic Discharge Caution



This integrated circuit can be damaged by ESD. Texas Instruments recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage.

ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet its published specifications.

9.5 Glossary

TI Glossary

This glossary lists and explains terms, acronyms, and definitions.

10 Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.

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PACKAGING INFORMATION

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan	Lead finish/ Ball material	MSL Peak Temp	Op Temp (°C)	Device Marking (4/5)	Samples
CD4027BE	ACTIVE	PDIP	N	16	25	RoHS & Green	NIPDAU	N / A for Pkg Type	-55 to 125	CD4027BE	Samples
CD4027BEE4	ACTIVE	PDIP	N	16	25	RoHS & Green	NIPDAU	N / A for Pkg Type	-55 to 125	CD4027BE	Samples
CD4027BF	ACTIVE	CDIP	J	16	25	Non-RoHS & Green	SNPB	N / A for Pkg Type	-55 to 125	CD4027BF	Samples
CD4027BF3A	ACTIVE	CDIP	J	16	25	Non-RoHS & Green	SNPB	N / A for Pkg Type	-55 to 125	CD4027BF3A	Samples
CD4027BM	LIFEBUY	SOIC	D	16	40	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-55 to 125	CD4027BM	
CD4027BM96	ACTIVE	SOIC	D	16	2500	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-55 to 125	CD4027BM	Samples
CD4027BM96E4	ACTIVE	SOIC	D	16	2500	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-55 to 125	CD4027BM	Samples
CD4027BMT	LIFEBUY	SOIC	D	16	250	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-55 to 125	CD4027BM	
CD4027BNSR	ACTIVE	SO	NS	16	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-55 to 125	CD4027B	Samples
CD4027BPW	LIFEBUY	TSSOP	PW	16	90	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-55 to 125	CM027B	
CD4027BPWR	ACTIVE	TSSOP	PW	16	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-55 to 125	CM027B	Samples
JM38510/05152BEA	ACTIVE	CDIP	J	16	25	Non-RoHS & Green	SNPB	N / A for Pkg Type	-55 to 125	JM38510/ 05152BEA	Samples
M38510/05152BEA	ACTIVE	CDIP	J	16	25	Non-RoHS & Green	SNPB	N / A for Pkg Type	-55 to 125	JM38510/ 05152BEA	Samples

⁽¹⁾ The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

RoHS Exempt: TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

Green: TI defines "Green" to mean the content of Chlorine (CI) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

⁽²⁾ RoHS: TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

PACKAGE OPTION ADDENDUM



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- (3) MSL, Peak Temp. The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.
- (4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.
- (5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.
- (6) Lead finish/Ball material Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

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OTHER QUALIFIED VERSIONS OF CD4027B, CD4027B-MIL:

Catalog: CD4027B

Military: CD4027B-MIL

NOTE: Qualified Version Definitions:

- Catalog TI's standard catalog product
- Military QML certified for Military and Defense Applications

PACKAGE MATERIALS INFORMATION

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TAPE AND REEL INFORMATION





A0	Dimension designed to accommodate the component width
В0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All dimensions are nominal

Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
CD4027BM96	SOIC	D	16	2500	330.0	16.4	6.5	10.3	2.1	8.0	16.0	Q1
CD4027BNSR	so	NS	16	2000	330.0	16.4	8.2	10.5	2.5	12.0	16.0	Q1
CD4027BPWR	TSSOP	PW	16	2000	330.0	12.4	6.9	5.6	1.6	8.0	12.0	Q1

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*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
CD4027BM96	SOIC	D	16	2500	340.5	336.1	32.0
CD4027BNSR	SO	NS	16	2000	356.0	356.0	35.0
CD4027BPWR	TSSOP	PW	16	2000	356.0	356.0	35.0

PACKAGE MATERIALS INFORMATION

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TUBE

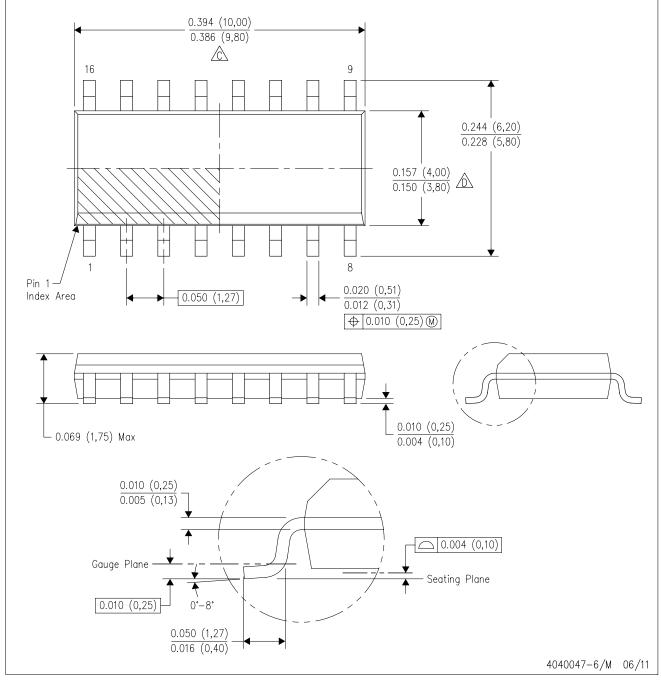


*All dimensions are nominal

Device	Package Name	Package Type	Pins	SPQ	L (mm)	W (mm)	T (µm)	B (mm)
CD4027BE	N	PDIP	16	25	506	13.97	11230	4.32
CD4027BE	N	PDIP	16	25	506	13.97	11230	4.32
CD4027BEE4	N	PDIP	16	25	506	13.97	11230	4.32
CD4027BEE4	N	PDIP	16	25	506	13.97	11230	4.32
CD4027BM	D	SOIC	16	40	507	8	3940	4.32
CD4027BPW	PW	TSSOP	16	90	530	10.2	3600	3.5

D (R-PDSO-G16)

PLASTIC SMALL OUTLINE

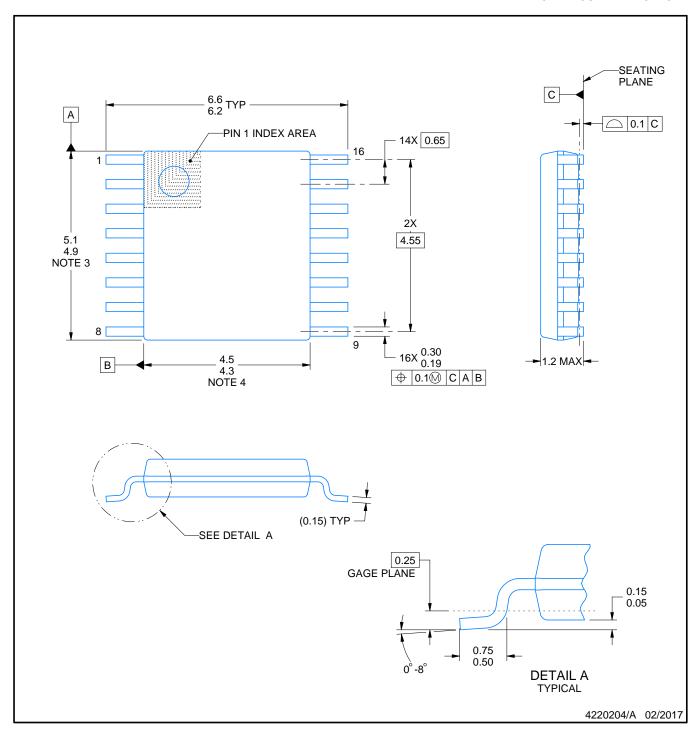


- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.006 (0,15) each side.
- Body width does not include interlead flash. Interlead flash shall not exceed 0.017 (0,43) each side.
- E. Reference JEDEC MS-012 variation AC.





SMALL OUTLINE PACKAGE



- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.

 2. This drawing is subject to change without notice.

 3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not
- exceed 0.15 mm per side.
- 4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.25 mm per side.
- 5. Reference JEDEC registration MO-153.



SMALL OUTLINE PACKAGE



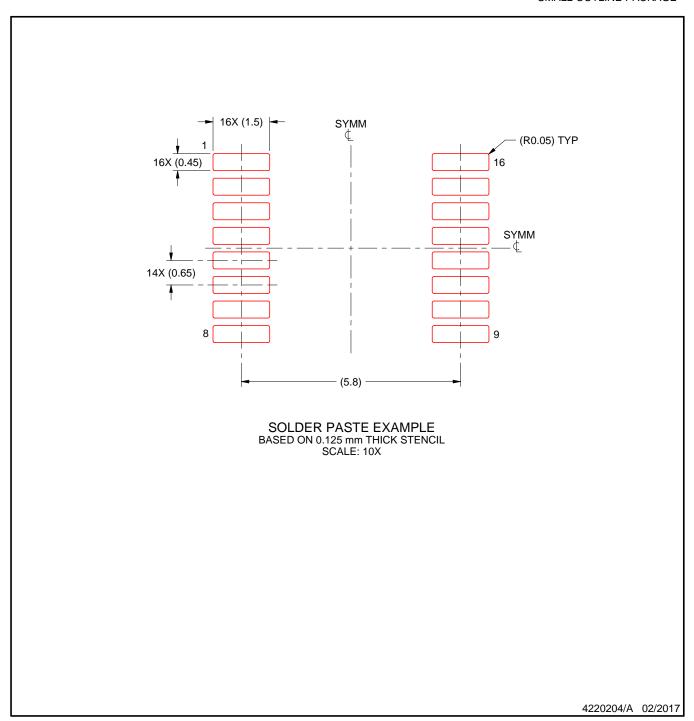
NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



SMALL OUTLINE PACKAGE



NOTES: (continued)

- 8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 9. Board assembly site may have different recommendations for stencil design.

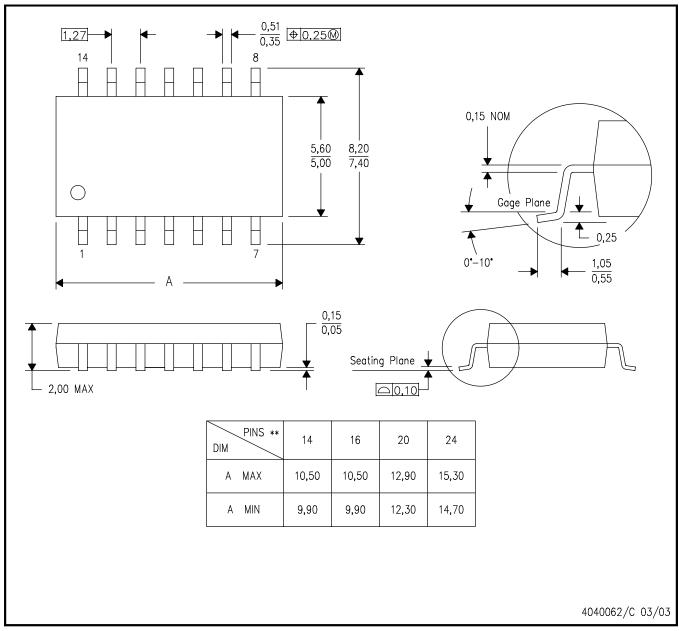


MECHANICAL DATA

NS (R-PDSO-G**)

14-PINS SHOWN

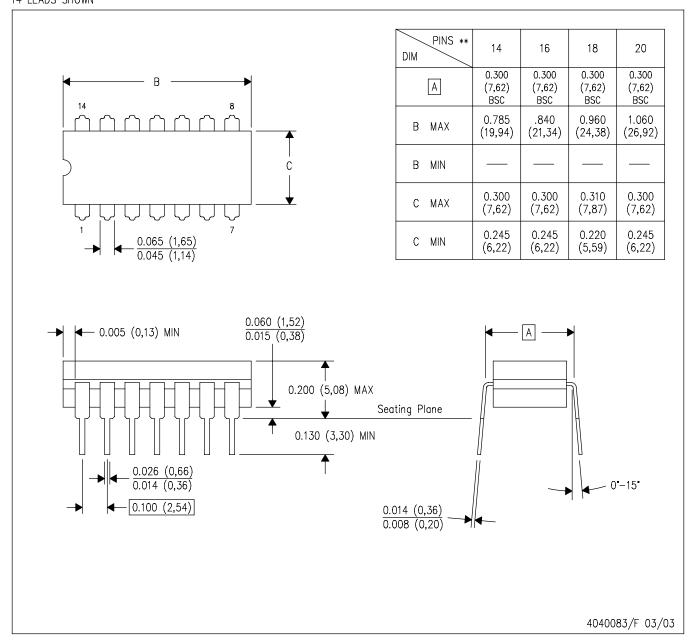
PLASTIC SMALL-OUTLINE PACKAGE



- All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. Body dimensions do not include mold flash or protrusion, not to exceed 0,15.



14 LEADS SHOWN

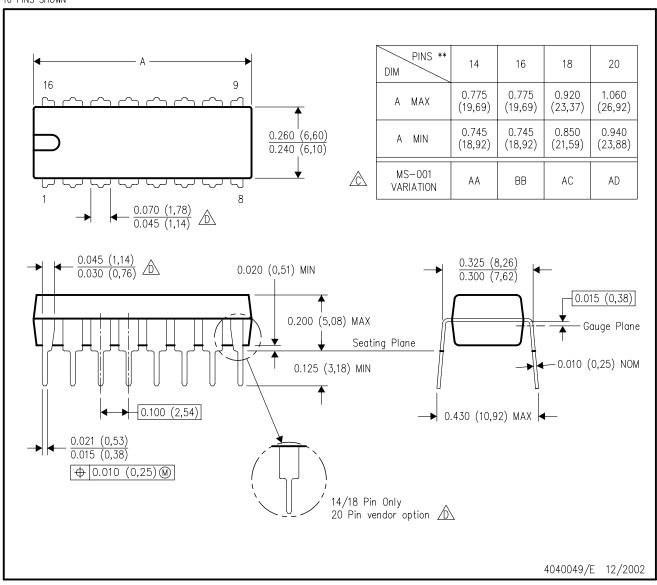


- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- C. This package is hermetically sealed with a ceramic lid using glass frit.
- D. Index point is provided on cap for terminal identification only on press ceramic glass frit seal only.
- E. Falls within MIL STD 1835 GDIP1-T14, GDIP1-T16, GDIP1-T18 and GDIP1-T20.

N (R-PDIP-T**)

PLASTIC DUAL-IN-LINE PACKAGE

16 PINS SHOWN

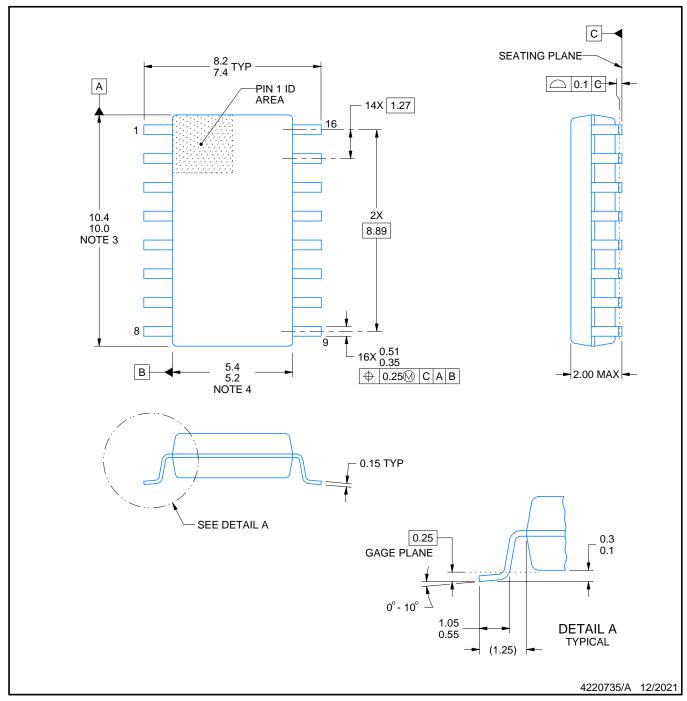


- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- Falls within JEDEC MS-001, except 18 and 20 pin minimum body length (Dim A).
- The 20 pin end lead shoulder width is a vendor option, either half or full width.





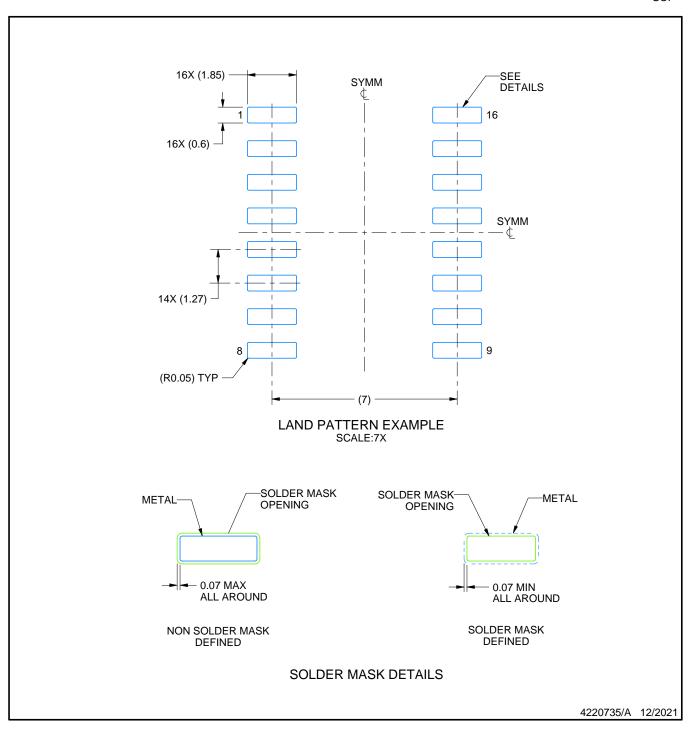
SOP



- 1. All linear dimensions are in millimeters. Dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.

 2. This drawing is subject to change without notice.
- 3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.15 mm, per side.
- 4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.25 mm, per side.

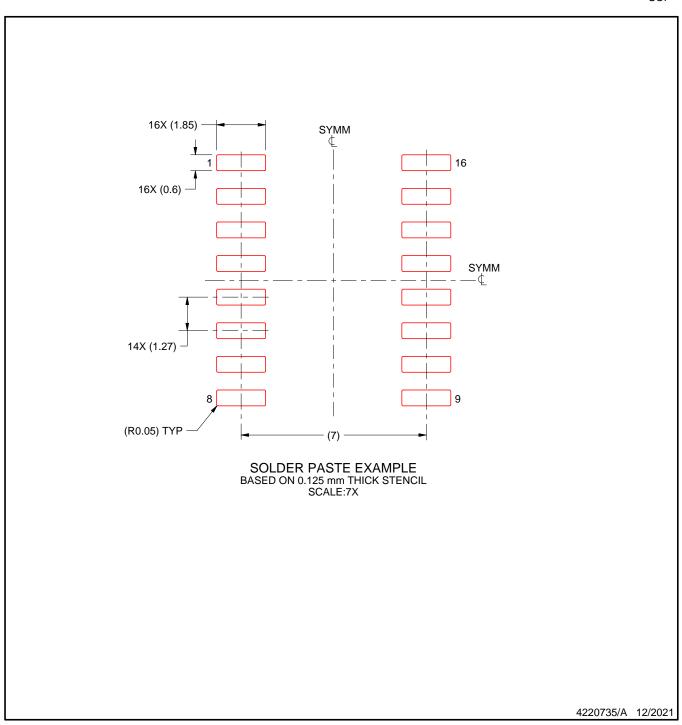
SOF



NOTES: (continued)

- 5. Publication IPC-7351 may have alternate designs.
- 6. Solder mask tolerances between and around signal pads can vary based on board fabrication site.

SOF



NOTES: (continued)

- 7. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 8. Board assembly site may have different recommendations for stencil design.



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